

Absolute Maximum Ratings (@ 25° C)

Parameter	Min	Тур	Max	Units
Input Power Dissipation	-	-	150 ¹	mW
Input Control Current	-	-	50	mA
Peak (10ms)	-	-	1	Α
Reverse Input Voltage	-	-	5	V
Relay Blocking Voltage	-	-	350	V
Total Power Dissipation	-	-	800 ²	mW
Isolation Voltage				
Input to Output	3750	-	-	V_{RMS}
Operational Temperature	-40	-	+85	°C
Storage Temperature	-40	-	+125	°C
Soldering Temperature				
DIP Package	-	-	+260	°C
Flatpack/Surface Mount				
Package	-	-	+220	°C
(10 Seconds Max.)				

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and effect its reliability.

Electrical Characteristics

Parameter	Conditions	Symbol	Min	Тур	Max	Units	
Relay Portion (Pins 7, 8) Output Characteristics @ 25°C							
Load Current (Continuous)	-	IL	-	-	120	mA	
Peak Load Current	10ms	I _{LPK}	-	-	350	mA	
On-Resistance	I _L =120mA	R _{ON}	-	-	35	Ω	
Off-State Leakage Current	V _L =350V	I _{LEAK}	-	-	1	μA	
Switching Speeds Turn-On	I _E =5mA, V _I =10V	T _{on}	-	-	2.5	ms	
Turn-Off	I _F =5mA, V _I =10V	T _{OFF}	-	-	2.5	ms	
Output Capacitance	50V; f=1MHz	C _{OUT}	-	25	-	pF	
Current Limit	I _F =5mA	I _{CL}	130	170	210	mA	
Relay Portion (Pins 1, 2) Input Characteristics @ 25°C							
Input Control Current	I _L =120mA	I _F	5	-	50	mA	
Input Dropout Current	-	I _F	0.4	0.7	-	mA	
Input Voltage Drop	I _F =5mA	V _F	0.9	1.2	1.4	V	
Reverse Input Voltage	-	V _R	-	-	5	V	
Reverse Input Current	V _R =5V	I _R	-	-	10	μА	

¹ Derate Linearly 1.33 mw/°C

² Derate Linearly 6.67 mw/°C

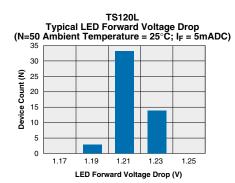


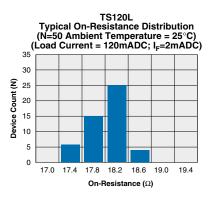
Electrical Characteristics (Continued)

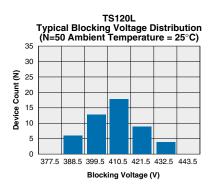
Parameter	Conditions	Symbol	Min	Тур	Max	Units	
Detector Portion (Pins 3, 4) Output Characteristics @ 25°C							
Phototransistor Blocking Voltage	I _C =10μA	BV _{CEO}	20	50	-	V	
Phototransistor Output Current	V _{CE} =5V, I _F =0mA	I _{CEO}	-	100	1000	nA	
Saturation Voltage	I _C =0.15mA, I _F =.05mA	V _{SAT}	-	0.5	0.8	V	
Current Transfer Ratio	I _F =0.05mA, V _{CE} =0.8V	CTR	300	1000	-	%	
Detector Portion (Pins 5, 6) Input Characteristics @ 25°C							
Input Control Current	$I_{\rm C}$ =2mA, $V_{\rm CE}$ =0.5V	I _F	2	1	100	mA	
Input Voltage Drop	I _F =5mA	V _F	0.9	1.2	1.4	V	
Input to Output Capacitance (Relay Only)	-	C _{I/O}	-	3	-	pF	
Capacitance Input to Output	-	-	-	3	-	pF	
Input to Output Isolation	-	V _{I/0}	3750	-	-	V_{RM}	

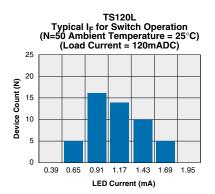


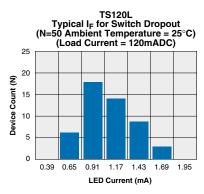
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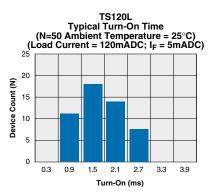


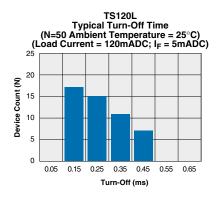


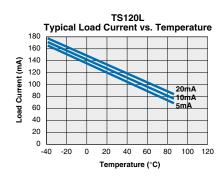


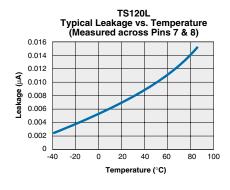


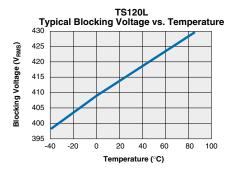


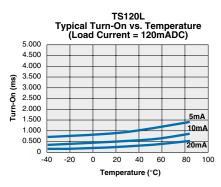


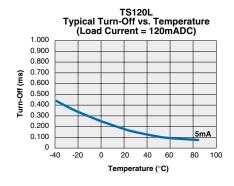








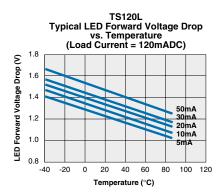


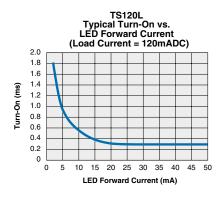


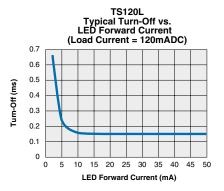
^{*} The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

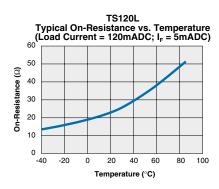


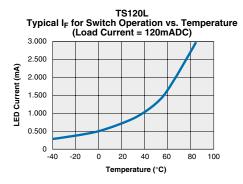
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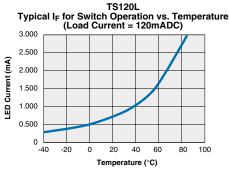


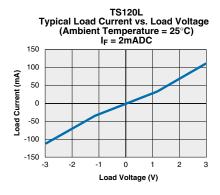


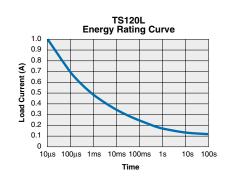


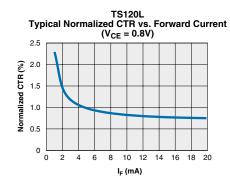


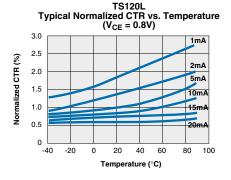


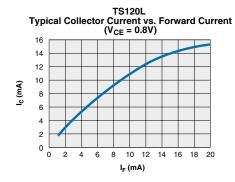










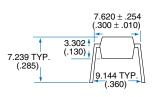


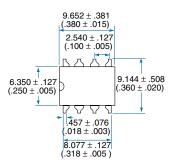
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MECHANICAL DIMENSIONS

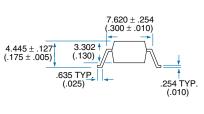
8 Pin DIP Through Hole (Standard)

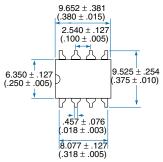




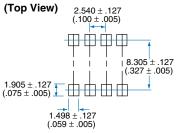
PC Board Pattern (Top View) 8-800 DIA. (.100 ± .005) (8-.031 DIA.) 6.350 ± .127 (.250 ± .005) 7.620 ± .127 (.300 ± .005)

8 Pin DIP Surface Mount ("S" Suffix)

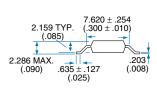


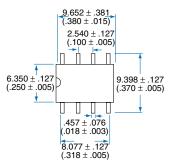


PC Board Pattern

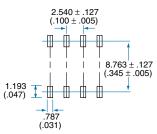


8 Pin Flatpack ("P" Suffix)





PC Board Pattern (Top View)

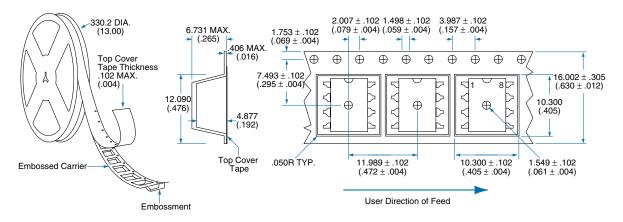


Dimensions mm (inches)

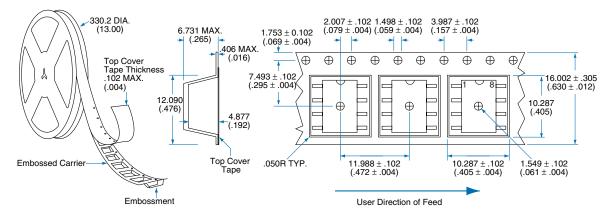


MECHANICAL DIMENSIONS

Tape and Reel Packaging for 8 Pin Surface Mount Package



Tape and Reel Packaging for 8 Pin Flatpack Package



Dimensions mm (inches)



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